## 2SC3311, 2SC3311A

### Silicon NPN Epitaxial Planar Type

For low-frequency amplification Complementary pair with 2SA1309 and 2SA1309A

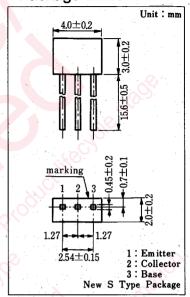
#### ■ Features

- •Ideal for high-density mounting
- •Automatic insertion by radial taping possible

### ■ Absolute Maximum Ratings (Ta=25°C)

Item		Symbol Value		Unit	
Collector-Base Voltage	2SC3311	77	30	77	
	2SC3311A	$V_{CBO}$	60		
Collector-Emitter Voltage	2SC3311	V	25	V	
	2SC3311A	VCEO	50	<b>v</b> .	
Emitter-Base Voltage		V <sub>EBO</sub>	7	v	
Peak Collector Voltage		ICP	200	mA	
Collector Current		Ic	100	mA	
Collector Power Dissipation		Pc	300	mW	
Junction Temperature		Ti	150	C C	
Storage Temperature		$T_{stg}$	-55~+150 <sub>C</sub>	·C	

#### ■ Package Dimensions



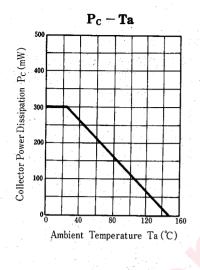
### ■ Electrical Characteristics (Ta=25°C)

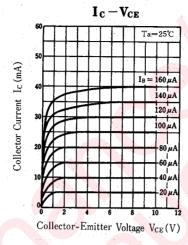
Item		Symbol	Condition	min.	typ.	max.	Unit
Collector Cutoff Current		Ісво	$V_{CB} = 10 \text{ V}, I_{E} = 0$	.0.	0	0.1	μA
		I <sub>CEO</sub>	$V_{CE} = 10 \text{ V}, I_{B} = 0$	00		1	μA
Collector-Base	lector-Base 2SC3311		$V_{CBO}$ $I_{C}=10 \mu A, I_{E}=0$	30			v
Voltage	2SC3311A	у сво	$1C=10 \mu A$ , $1E=0$	60			V
Collector-Emitter Voltage	2SC3311	V <sub>CEO</sub>	$I_C=2 \text{ mA}, I_B=0$	. 25			v
	2SC3311A	V CEO		50			
Emitter-Base Voltage		V <sub>EBO</sub>	$I_E = 10 \mu\text{A}, \ I_C = 0$	7			V
DC Current Gain		h <sub>FE</sub> *	$V_{CE}$ =10 V, $I_{C}$ =2 mA	160		460	
Collector-Emitter Saturation Voltage V		V <sub>CE(sat)</sub>	$I_C=50 \text{ mA}, I_B=5 \text{ mA}$			0.3	V
Transition Frequency		f <sub>T</sub>	$V_{CB}=10V, I_{E}=-1mA, f=200MHz$		150		MHz
Collector Output Capacitance		Сов	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		3.5		pF

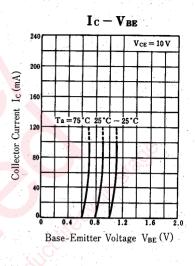
\*hfe Ranking

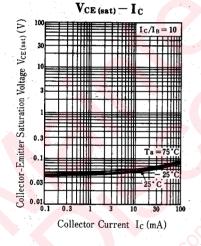
Rank	Q	R	S
h <sub>FE</sub>	160~260	210~340	290~460

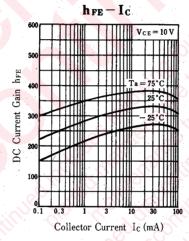


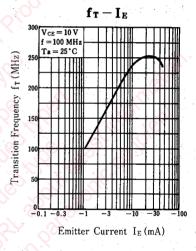


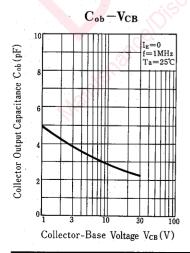


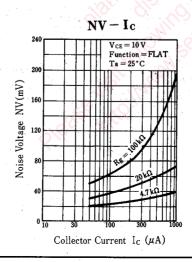












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